CD54AC273, CD74AC273
CD54ACT273, CD74ACT273

August 1998 - Revised April 2000

Octal D Flip-Flop with Reset

Features

- **Buffered Inputs**
- **Typical Propagation Delay**
  - **6.5ns at V_{CC} = 5V, T_A = 25°C, C_L = 50pF**
- **Exceeds 2kV ESD Protection MIL-STD-883, Method 3015**
- **SCR-Latchup-Resistant CMOS Process and Circuit Design**
- **Speed of Bipolar FAST™/AS/S with Significantly Reduced Power Consumption**
- **Balanced Propagation Delays**
- **AC Types Feature 1.5V to 5.5V Operation and Balanced Noise Immunity at 30% of the Supply**
- **±24mA Output Drive Current**
  - **Fanout to 15 FAST™ ICs**
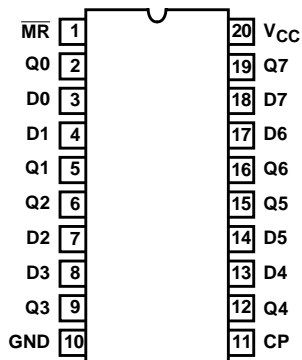 - **Drives 50Ω Transmission Lines**

Description

The 'AC273 and 'ACT273 devices are octal D-type flip-flops with reset that utilize advanced CMOS logic technology. Information at the D input is transferred to the Q output on the positive-going edge of the clock pulse. All eight flip-flops are controlled by a common clock (CP) and a common reset ($\overline{MR}$). Resetting is accomplished by a low voltage level independent of the clock.

Ordering Information

PART NUMBER	TEMPERATURE RANGE	PACKAGE
CD74AC273E	-40°C to 85°C	20 Ld PDIP
CD54AC273F3A	-55°C to 125°C	20 Ld CDIP
CD74ACT273E	-40°C to 85°C	20 Ld PDIP
CD54ACT273F3A	-55°C to 125°C	20 Ld CDIP
CD74AC273M	-40°C to 85°C	20 Ld SOIC
CD74ACT273M	-40°C to 85°C	20 Ld SOIC

NOTES:

1. When ordering, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.

2. Wafer and die for this part number is available which meets all electrical specifications. Please contact your local sales office for ordering information.

Pinout

**CD54AC273, CD54ACT273
(CDIP)
CD74AC273, CD74ACT273
(PDIP, SOIC)**
TOP VIEW

$\overline{MR}$	1		20	V_{CC}
Q0	2		19	Q7
D0	3		18	D7
D1	4		17	D6
Q1	5		16	Q6
Q2	6		15	Q5
D2	7		14	D5
D3	8		13	D4
Q3	9		12	Q4
GND	10		11	CP

CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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Functional Diagram

TRUTH TABLE

INPUTS			OUTPUTS
RESET **($\overline{MR}$)**	**CLOCK** **CP**	**DATA** **Dn**	**Qn**
L	X	X	L
H	↑	H	H
H	↑	L	L
H	L	X	Q0

H = High level (steady state), L = Low level (steady state), X = Irrelevant, ↑ = Transition from Low to High level, Q0 = The level of Q before the indicated steady-state input conditions were established.

Absolute Maximum Ratings

DC Supply Voltage, V_{CC} . . . . -0.5V to 6V
DC Input Diode Current, I_{IK}
   For V_I < -0.5V or V_I > V_{CC} + 0.5V . . . . ±20mA
DC Output Diode Current, I_{OK}
   For V_O < -0.5V or V_O > V_{CC} + 0.5V . . . . ±50mA
DC Output Source or Sink Current per Output Pin, I_O
   For V_O > -0.5V or V_O < V_{CC} + 0.5V . . . . ±50mA
DC V_{CC} or Ground Current, $I_{CC \, or} \, I_{GND}$ (Note 3) . . . . ±100mA

Thermal Information

Thermal Resistance, θ_{JA} (Typical, Note 5)
   E Package . . . . .69°C/W
   M Package . . . . .58°C/W
Maximum Junction Temperature (Plastic Package) . . . . 150°C
Maximum Storage Temperature Range . . . .-65°C to 150°C
Maximum Lead Temperature (Soldering 10s) . . . . 300°C

Operating Conditions

Temperature Range, T_A
   CD54AC273, CD54ACT273 . . . . -55°C to 125°C
   CD74AC273, CD74ACT273 . . . . -40°C to 85°C
Supply Voltage Range, V_{CC} (Note 4)
   AC Types. . . . . .1.5V to 5.5V
   ACT Types . . . . .4.5V to 5.5V
DC Input or Output Voltage, V_I, V_O . . . . 0V to V_{CC}
Input Rise and Fall Slew Rate, dt/dv
   AC Types, 1.5V to 3V . . . . 50ns (Max)
   AC Types, 3.6V to 5.5V. . . . . 20ns (Max)
   ACT Types, 4.5V to 5.5V. . . . . 10ns (Max)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

3. For up to 4 outputs per device, add ±25mA for each additional output.

4. Unless otherwise specified, all voltages are referenced to ground.

5. The package thermal impedance is calculated in accordance with JESD 51.

DC Electrical Specifications

PARAMETER	SYMBOL	TEST CONDITIONS V_I (V)	TEST CONDITIONS I_O (mA)	V_{CC} (V)	25°C MIN	25°C MAX	-40°C TO 85°C MIN	-40°C TO 85°C MAX	-55°C TO 125°C MIN	-55°C TO 125°C MAX	UNITS
AC TYPES											
High Level Input Voltage	V_{IH}	-	-	1.5	1.2	-	1.2	-	1.2	-	V
				3	2.1	-	2.1	-	2.1	-	V
				5.5	3.85	-	3.85	-	3.85	-	V
Low Level Input Voltage	V_{IL}	-	-	1.5	-	0.3	-	0.3	-	0.3	V
				3	-	0.9	-	0.9	-	0.9	V
				5.5	-	1.65	-	1.65	-	1.65	V
High Level Output Voltage	V_{OH}	V_{IH} or V_{IL}	-0.05	1.5	1.4	-	1.4	-	1.4	-	V
			-0.05	3	2.9	-	2.9	-	2.9	-	V
			-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-4	3	2.58	-	2.48	-	2.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V

DC Electrical Specifications (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS V_I (V)	TEST CONDITIONS I_O (mA)	V_{CC} (V)	25°C MIN	25°C MAX	-40°C TO 85°C MIN	-40°C TO 85°C MAX	-55°C TO 125°C MIN	-55°C TO 125°C MAX	UNITS
Low Level Output Voltage	V_{OL}	V_{IH} or V_{IL}	0.05	1.5	-	0.1	-	0.1	-	0.1	V
			0.05	3	-	0.1	-	0.1	-	0.1	V
			0.05	4.5	-	0.1	-	0.1	-	0.1	V
			12	3	-	0.36	-	0.44	-	0.5	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	I_I	V_{CC} or GND	-	5.5	-	±0.1	-	±1	-	±1	µA
Quiescent Supply Current MSI	I_{CC}	V_{CC} or GND	0	5.5	-	8	-	80	-	160	µA
ACT TYPES											
High Level Input Voltage	V_{IH}	-	-	4.5 to 5.5	2	-	2	-	2	-	V
Low Level Input Voltage	V_{IL}	-	-	4.5 to 5.5	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage	V_{OH}	V_{IH} or V_{IL}	-0.05	4.5	4.4	-	4.4	-	4.4	-	V
			-24	4.5	3.94	-	3.8	-	3.7	-	V
			-75 (Note 6, 7)	5.5	-	-	3.85	-	-	-	V
			-50 (Note 6, 7)	5.5	-	-	-	-	3.85	-	V
Low Level Output Voltage	V_{OL}	V_{IH} or V_{IL}	0.05	4.5	-	0.1	-	0.1	-	0.1	V
			24	4.5	-	0.36	-	0.44	-	0.5	V
			75 (Note 6, 7)	5.5	-	-	-	1.65	-	-	V
			50 (Note 6, 7)	5.5	-	-	-	-	-	1.65	V
Input Leakage Current	I_I	V_{CC} or GND	-	5.5	-	±0.1	-	±1	-	±1	µA
Quiescent Supply Current MSI	I_{CC}	V_{CC} or GND	0	5.5	-	8	-	80	-	160	µA
Additional Supply Current per Input Pin TTL Inputs High 1 Unit Load	ΔI_{CC}	V_{CC} -2.1	-	4.5 to 5.5	-	2.4	-	2.8	-	3	mA

NOTES:

6. Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

7. Test verifies a minimum 50Ω transmission-line-drive capability at 85°C, 75Ω at 125°C.

ACT Input Load Table

INPUT	UNIT LOAD
Dn	0.5
$\overline{MR}$	0.57
CP	1

NOTE: Unit load is ΔI_{CC} limit specified in DC Electrical Specifications Table, e.g., 2.4mA max at 25°C.

CD54AC273, CD74AC273, CD54ACT273, CD74ACT273

Prerequisite For Switching Function

PARAMETER	SYMBOL	V_{CC} (V)	-40°C TO 85°C MIN	-40°C TO 85°C MAX	-55°C TO 125°C MIN	-55°C TO 125°C MAX	UNITS
AC TYPES							
Data to CP Set-Up Time	t_{SU}	1.5	2	-	2	-	ns
		3.3 (Note 9)	2	-	2	-	ns
		5 (Note 10)	2	-	2	-	ns
Hold Time	t_H	1.5	2	-	2	-	ns
		3.3	2	-	2	-	ns
		5	2	-	2	-	ns
Removal Time, $\overline{MR}$ to CP	t_{REM}	1.5	2	-	2	-	ns
		3.3	2	-	2	-	ns
		5	2	-	2	-	ns
$\overline{MR}$ Pulse Width	t_W	1.5	55	-	63	-	ns
		3.3	6.1	-	7	-	ns
		5	4.4	-	5	-	ns
CP Pulse Width	t_W	1.5	55	-	63	-	ns
		3.3	6.1	-	7	-	ns
		5	4.4	-	5	-	ns
CP Frequency	f_{MAX}	1.5	9	-	8	-	MHz
		3.3	81	-	71	-	MHz
		5	114	-	100	-	MHz
ACT TYPES							
Data to CP Set-Up Time	t_{SU}	5 (Note 10)	2	-	2	-	ns
Hold Time	t_H	5	2	-	2	-	ns
Removal Time $\overline{MR}$ to CP	t_{REM}	5	2	-	2	-	ns
$\overline{MR}$ Pulse Width	t_W	5	4.4	-	5	-	ns
CP Pulse Width	t_W	5	5.3	-	6	-	ns
CP Frequency	f_{MAX}	5	97	-	85	-	MHz

Switching Specifications Input t_r, t_f = 3ns, C_L = 50pF (Worst Case)

PARAMETER	SYMBOL	V_{CC} (V)	-40°C TO 85°C MIN	TYP	MAX	-55°C TO 125°C MIN	TYP	MAX	UNITS
AC TYPES									
Propagation Delay, CP to Qn	t_{PLH}, t_{PHL}	1.5	-	-	154	-	-	169	ns
		3.3 (Note 9)	4.9	-	17.2	4.7	-	18.9	ns
		5 (Note 10)	3.5	-	12.3	3.4	-	13.5	ns

Switching Specifications Input t_r, t_f = 3ns, C_L = 50pF (Worst Case) **(Continued)**

PARAMETER	SYMBOL	V_{CC} (V)	-40°C TO 85°C			-55°C TO 125°C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Propagation Delay, $\overline{MR}$ to Qn	t_{PLH}, t_{PHL}	1.5	-	-	154	-	-	169	ns
		3.3	4.9	-	17.2	4.7	-	18.9	ns
		5	3.5	-	12.3	3.4	-	13.5	ns
Input Capacitance	C_I	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C_{PD} (Note 11)	-	-	45	-	-	45	-	pF
ACT TYPES									
Propagation Delay, CP to Qn	t_{PLH}, t_{PHL}	5 (Note 10)	3.5	-	12.3	3.4	-	13.5	ns
Propagation Delay, $\overline{MR}$ to Qn	t_{PLH}, t_{PHL}	5	3.5	-	12.3	3.4	-	13.5	ns
Input Capacitance	C_I	-	-	-	10	-	-	10	pF
Power Dissipation Capacitance	C_{PD} (Note 11)	-	-	45	-	-	45	-	pF

NOTES:

8. Limits tested 100%.

9. 3.3V Min is at 3.6V, Max is at 3V.

10. 5V Min is at 5.5V, Max is at 4.5V.

11. C_{PD} is used to determine the dynamic power consumption per flip-flop.
   AC: $P_D = C_{PD} V_{CC}^2 f_i = \Sigma (C_L V_{CC}^2 f_o)$
   ACT: $P_D = C_{PD} V_{CC}^2 f_i + \Sigma (C_L V_{CC}^2 f_o) + V_{CC} \Delta I_{CC}$ where f_i = input frequency, f_o = output frequency, C_L = output load capacitance, V_{CC} = supply voltage.
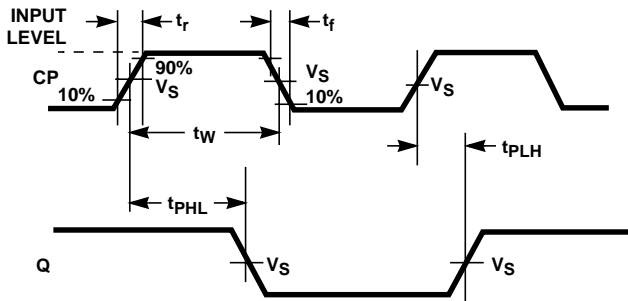

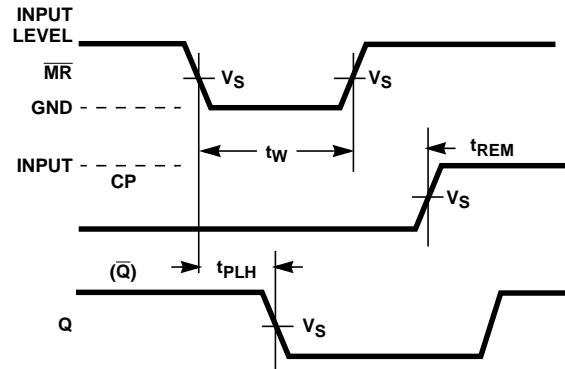**FIGURE 1. PROPAGATION DELAY TIMES AND CLOCK PULSE WIDTH**

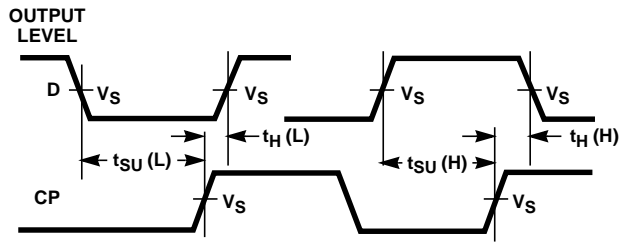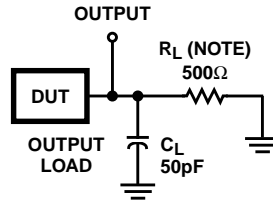**FIGURE 2. PREREQUISITE AND PROPAGATION DELAY TIMES FOR MASTER RESET**

FIGURE 3. PREREQUISITE FOR CLOCK

NOTE: For AC Series Only: When V_{CC} = 1.5V, R_L = 1kΩ.

	AC	ACT
Input Level	V_{CC}	3V
Input Switching Voltage, V_S	0.5 V_{CC}	1.5V
Output Switching Voltage, V_S	0.5 V_{CC}	0.5 V_{CC}

FIGURE 4. PROPAGATION DELAY TIMES

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